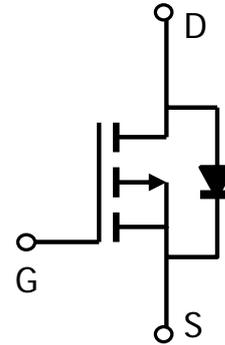


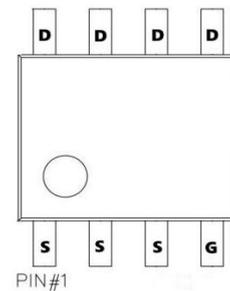
General Description

The AO4485 uses advanced trench technology to provide excellent $R_{DS(ON)}$ with low gate charge. This device is suitable for use as a DC-DC converter application.



Features

V_{DS} (V) = -40V
 I_D = -10A
 $R_{DS(ON)} < 15m\Omega$ ($V_{GS} = -10V$)
 $R_{DS(ON)} < 20m\Omega$ ($V_{GS} = -4.5V$)



Absolute Maximum Ratings $T_J=25^\circ\text{C}$ unless otherwise noted

| Parameter | Symbol | 10 Sec | Steady State | Units | |
|---|----------------|------------------------|--------------|------------------|----|
| Drain-Source Voltage | V_{DS} | -40 | | V | |
| Gate-Source Voltage | V_{GS} | ± 20 | | V | |
| Continuous Drain Current ^A | I_D | $T_A=25^\circ\text{C}$ | -12 | A | |
| | | $T_A=70^\circ\text{C}$ | -9 | | |
| Pulsed Drain Current ^B | I_{DM} | -120 | | A | |
| Avalanche Current ^G | I_{AR} | -28 | | | |
| Repetitive avalanche energy $L=0.3\text{mH}$ ^G | E_{AR} | 118 | | | mJ |
| Power Dissipation ^A | P_D | $T_A=25^\circ\text{C}$ | 3.1 | 1.7 | W |
| | | $T_A=70^\circ\text{C}$ | 2.0 | 1.1 | |
| Junction and Storage Temperature Range | T_J, T_{STG} | -55 to 150 | | $^\circ\text{C}$ | |

Thermal Characteristics

| Parameter | Symbol | Typ | Max | Units |
|--|-----------------|--------------|-----|--------------------|
| Maximum Junction-to-Ambient ^A | $R_{\theta JA}$ | 31 | 40 | $^\circ\text{C/W}$ |
| Maximum Junction-to-Ambient ^A | | Steady State | 59 | |
| Maximum Junction-to-Lead ^C | $R_{\theta JL}$ | 16 | 24 | $^\circ\text{C/W}$ |

Electrical Characteristics (T_J=25°C unless otherwise noted)

| Symbol | Parameter | Conditions | Min | Typ | Max | Units |
|-----------------------------|---------------------------------------|--|------|------------|----------|-------|
| STATIC PARAMETERS | | | | | | |
| BV _{DSS} | Drain-Source Breakdown Voltage | I _D = -250μA, V _{GS} = 0V | -40 | | | V |
| I _{DSS} | Zero Gate Voltage Drain Current | V _{DS} = -40V, V _{GS} = 0V T _J = 55°C | | | -1 -5 | μA |
| I _{GSS} | Gate-Body leakage current | V _{DS} = 0V, V _{GS} = ±20V | | | ±100 | nA |
| V _{GS(th)} | Gate Threshold Voltage | V _{DS} = V _{GS} , I _D = -250μA | -1 | -1.5 | -2.5 | V |
| I _{D(ON)} | On state drain current | V _{GS} = -10V, V _{DS} = -5V | -120 | | | A |
| R _{DS(ON)} | Static Drain-Source On-Resistance | V _{GS} = -10V, I _D = -10A V _{GS} = -4.5V, I _D = -8A | | 12.5 16 | 15 20 | mΩ |
| g _{FS} | Forward Transconductance | V _{DS} = -5V, I _D = -10A | | 25 | | S |
| V _{SD} | Diode Forward Voltage | I _S = -1A, V _{GS} = 0V | | -0.7 | -1 | V |
| I _S | Maximum Body-Diode Continuous Current | | | | -3 | A |
| DYNAMIC PARAMETERS | | | | | | |
| C _{iss} | Input Capacitance | V _{GS} =0V, V _{DS} =-20V, f=1MHz | | 2500 | 3000 | pF |
| C _{oss} | Output Capacitance | | | 260 | | pF |
| C _{riss} | Reverse Transfer Capacitance | | | 180 | | pF |
| R _g | Gate resistance | V _{GS} =0V, V _{DS} =0V, f=1MHz | 2.5 | 4 | 6 | Ω |
| SWITCHING PARAMETERS | | | | | | |
| Q _g (10V) | Total Gate Charge | V _{GS} =-10V, V _{DS} =-20V, I _D =-10A | | 42 | 55 | nC |
| Q _g (4.5V) | Total Gate Charge | | | 18.6 | | nC |
| Q _{gs} | Gate Source Charge | | | 7 | | nC |
| Q _{gd} | Gate Drain Charge | | | 8.6 | | nC |
| t _{D(on)} | Turn-On DelayTime | V _{GS} =-10V, V _{DS} =-20V, R _L = 2Ω, R _{GEN} =3Ω | | 9.4 | | ns |
| t _r | Turn-On Rise Time | | | 20 | | ns |
| t _{D(off)} | Turn-Off DelayTime | | | 55 | | ns |
| t _f | Turn-Off Fall Time | | | 30 | | ns |
| t _{rr} | Body Diode Reverse Recovery Time | I _F =-10A, dI/dt=100A/μs | | 38 | 49 | ns |
| Q _{rr} | Body Diode Reverse Recovery Charge | I _F =-10A, dI/dt=100A/μs | | 47 | | nC |

A: The value of R_{θJA} is measured with the device mounted on 1in² FR-4 board with 2oz. Copper, in a still air environment with T_A = 25°C. The value in any given application depends on the user's specific board design.

B: Repetitive rating, pulse width limited by junction temperature.

C: The R_{θJA} is the sum of the thermal impedance from junction to lead R_{θJL} and lead to ambient.

D: The static characteristics in Figures 1 to 6 are obtained using t ≤ 300μs pulses, duty cycle 0.5% max.

E: These tests are performed with the device mounted on 1 in² FR-4 board with 2oz. Copper, in a still air environment with T_A=25°C. The SOA curve provides a single pulse rating.

F: The current rating is based on the t ≤ 10s thermal resistance rating.

G: E_{AR} and I_{AR} ratings are based on low frequency and duty cycles to keep T_J=25C.

TYPICAL ELECTRICAL AND THERMAL CHARACTERISTICS

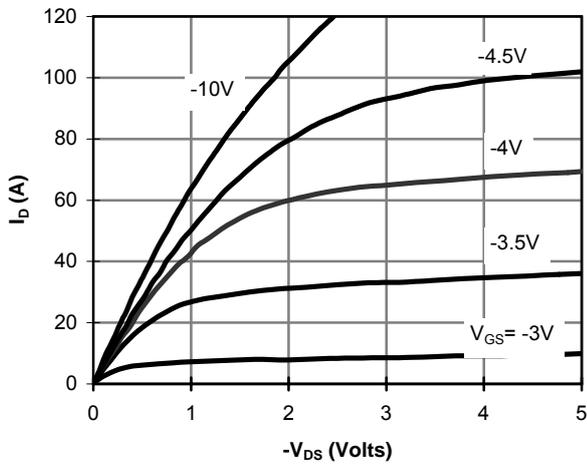


Figure 1: On-Region Characteristics

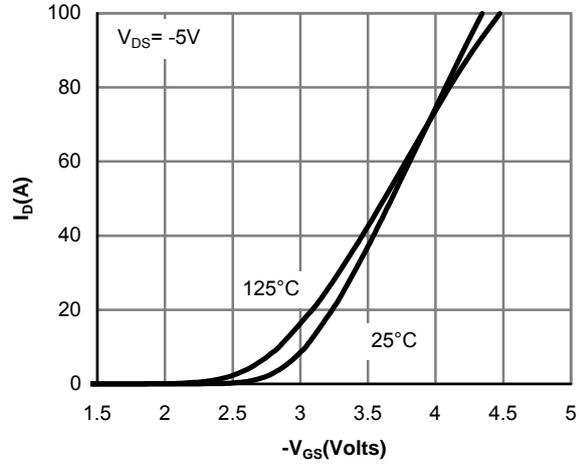


Figure 2: Transfer Characteristics

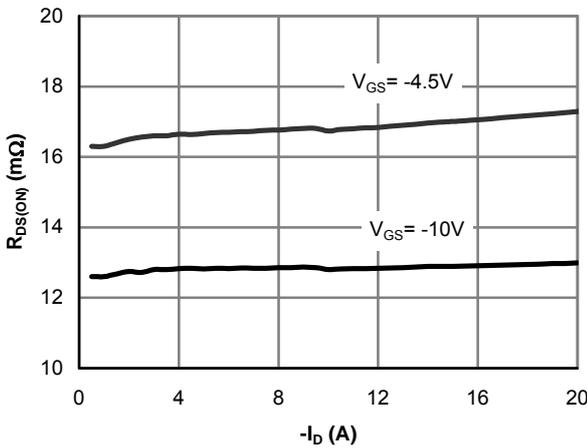


Figure 3: On-Resistance vs. Drain Current and Gate Voltage

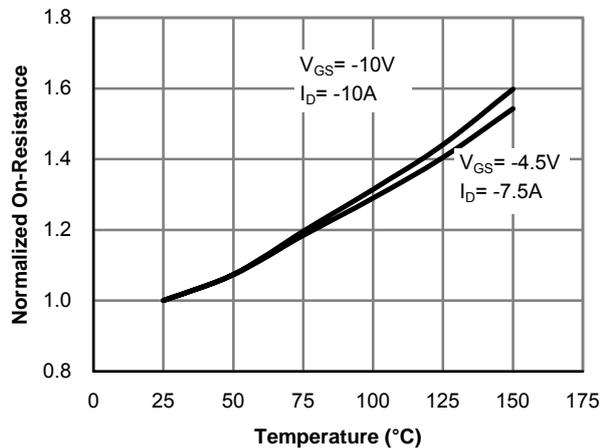


Figure 4: On-Resistance vs. Junction Temperature

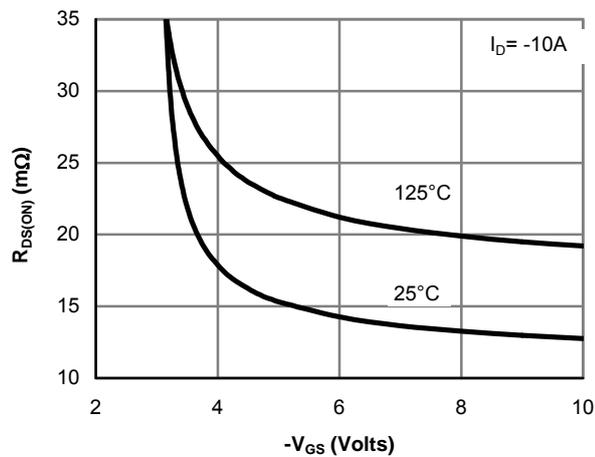


Figure 5: On-Resistance vs. Gate-Source Voltage

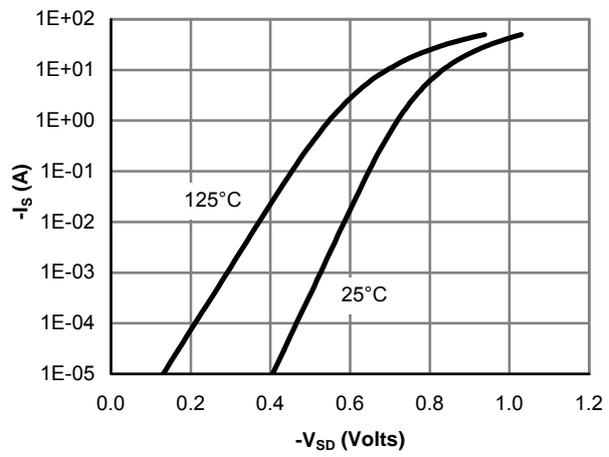


Figure 6: Body-Diode Characteristics

TYPICAL ELECTRICAL AND THERMAL CHARACTERISTICS

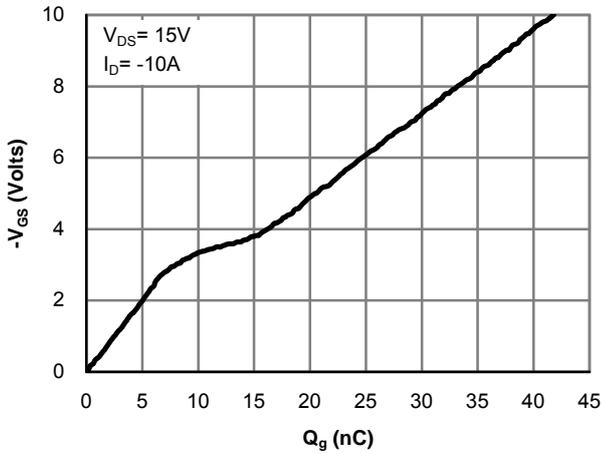


Figure 7: Gate-Charge Characteristics

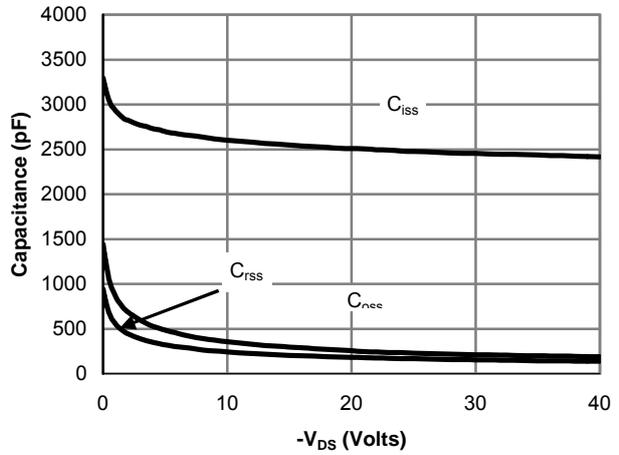


Figure 8: Capacitance Characteristics

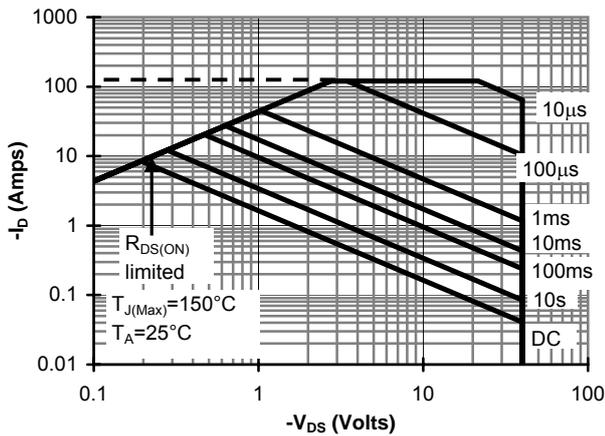


Figure 9: Maximum Forward Biased Safe Operating Area (Note E)

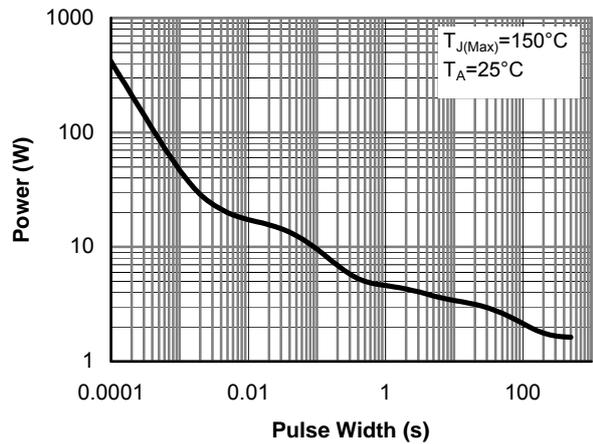


Figure 10: Single Pulse Power Rating Junction-to-Ambient (Note E)

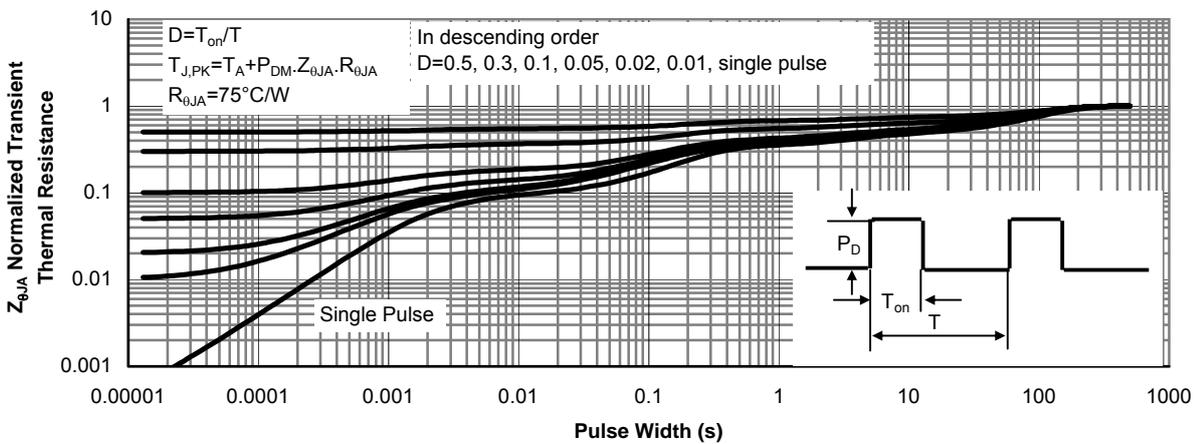
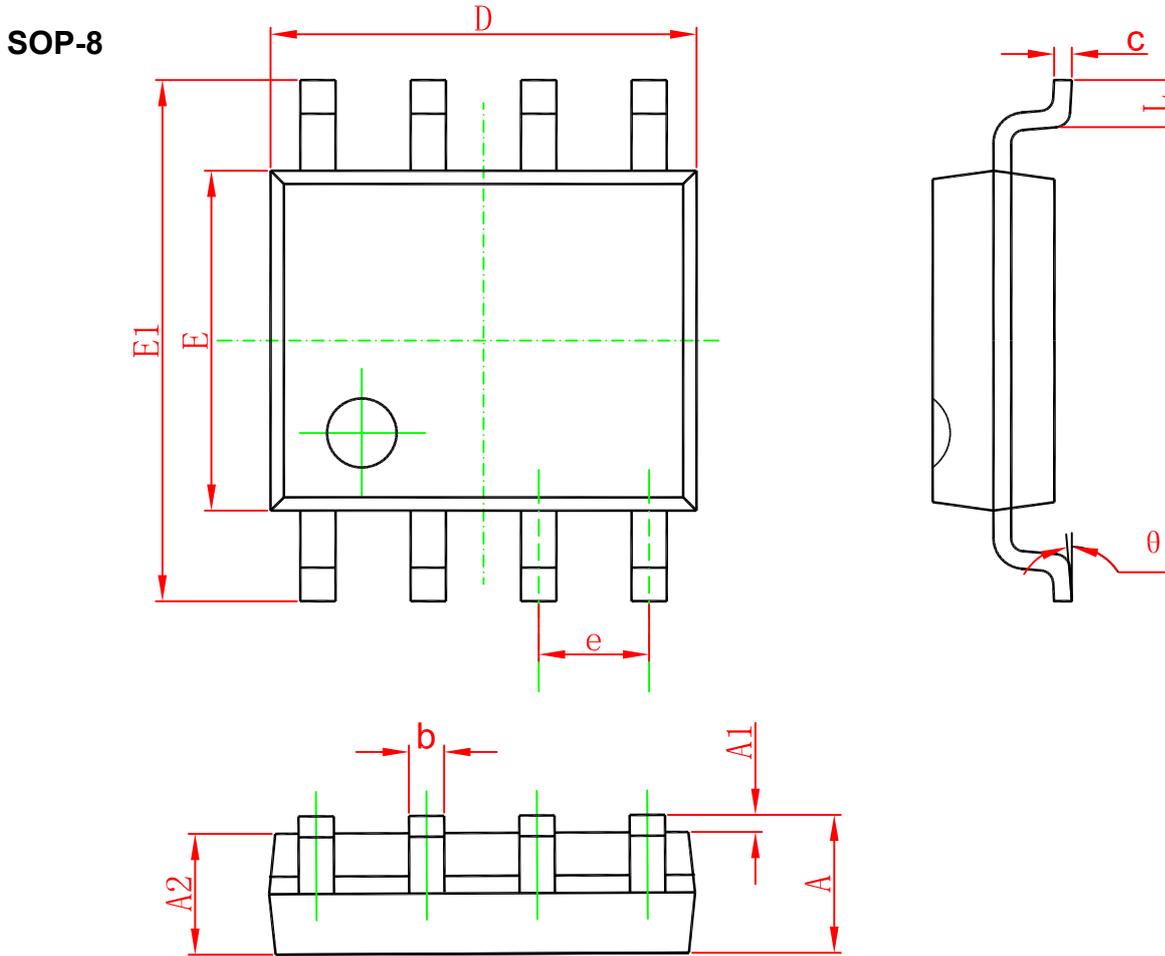


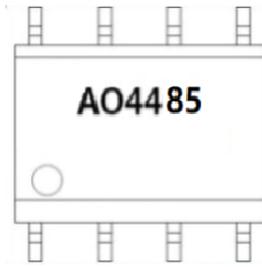
Figure 11: Normalized Maximum Transient Thermal Impedance (Note E)

PACKAGE OUTLINE DIMENSIONS



| Symbol | Dimensions In Millimeters | | Dimensions In Inches | |
|----------|---------------------------|-------|----------------------|-------|
| | Min | Max | Min | Max |
| A | 1.350 | 1.750 | 0.053 | 0.069 |
| A1 | 0.100 | 0.250 | 0.004 | 0.010 |
| A2 | 1.350 | 1.550 | 0.053 | 0.061 |
| b | 0.330 | 0.510 | 0.013 | 0.020 |
| c | 0.170 | 0.250 | 0.006 | 0.010 |
| D | 4.700 | 5.100 | 0.185 | 0.200 |
| E | 3.800 | 4.000 | 0.150 | 0.157 |
| E1 | 5.800 | 6.200 | 0.228 | 0.244 |
| e | 1.270(BSC) | | 0.050(BSC) | |
| L | 0.400 | 1.270 | 0.016 | 0.050 |
| θ | 0° | 8° | 0° | 8° |

Marking



Ordering information

| Order code | Package | Baseqty | Deliverymode |
|------------|---------|---------|---------------|
| AO4485 | SOP-8 | 3000 | Tape and reel |